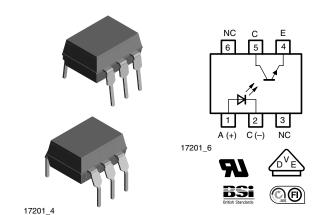


## Vishay Semiconductors

## **Optocoupler, Phototransistor Output**



#### **DESCRIPTION**

The TCDT1120(G) series consists of a phototransistor optically coupled to a gallium arsenide infrared emitting diode in a 6 lead plastic dual in line package.

### **FEATURES**

- High common mode rejection
- Four CTR groups available
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC





#### **APPLICATIONS**

- Switch-mode power supplies
- Line receiver
- Computer peripheral interface
- Microprocessor system interface
- Reinforced isolation provides circuit protection against electrical shock (safety class II)
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
  - for appl. class I IV at mains voltage ≤ 300 V
  - for appl. class I III at mains voltage  $\leq 600~\text{V}$  according to DIN EN 60747-5-5

### **AGENCY APPROVALS**

- UL1577, file no. E52744, double protection
- BSI IEC 60950 IEC 60065
- DIN EN 60747-5-5 (VDE 0884)
- FIMKO
- cUL tested to CSA 22.2 bulletin 5A

ORDER INFORMATION (1)						
PART	REMARKS					
TCDT1120	CTR > 40 %, DIP-6					
TCDT1122	CTR 63 % to 125 %, DIP-6					
TCDT1123	CTR 100 % to 200 %, DIP-6					
TCDT1124	CTR 160 % to 320 %, DIP-6					
TCDT1120G	CTR > 40 %, DIP-6					
TCDT1122G	CTR 63 % to 125 %, DIP-6					
TCDT1123G	CTR 100 % to 200 %, DIP-6					
TCDT1124G	CTR 160 % to 320 %, DIP-6					

#### Note

 $^{(1)}$  G = leadform 10.16 mm; G is not marked on the body.

## TCDT1120, TCDT1120G

## Vishay Semiconductors Optocoupler, Phototransistor Output



ABSOLUTE MAXIMUM RATINGS (1)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		$V_R$	5	V				
Forward current		I <sub>F</sub>	60	mA				
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	3	Α				
Power dissipation		P <sub>diss</sub>	100	mW				
Junction temperature		T <sub>j</sub>	125	°C				
OUTPUT								
Collector emitter voltage		V <sub>CEO</sub>	70	V				
Emitter collector voltage		V <sub>ECO</sub>	7	V				
Collector current		I <sub>C</sub>	50	mA				
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA				
Power dissipation		P <sub>diss</sub>	150	mW				
Junction temperature		T <sub>j</sub>	125	°C				
COUPLER								
Isolation test voltage (RMS)	t = 1 s	V <sub>ISO</sub>	5000	$V_{RMS}$				
Total power dissipation		P <sub>tot</sub>	250	mW				
Ambient temperature range		T <sub>amb</sub>	- 55 to + 100	°C				
Storage temperature range		T <sub>stg</sub>	- 55 to + 125	°C				
Soldering temperature (2)	2 mm from case, t ≤ 10 s	T <sub>sld</sub>	260	°C				

### Notes

<sup>(2)</sup> Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTCS (1)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	$I_F = 50 \text{ mA}$	$V_{F}$		1.25	1.6	٧		
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C <sub>j</sub>		50		pF		
OUTPUT								
Collector base voltage	I <sub>C</sub> = 100 μA	$V_{CBO}$	90			٧		
Collector emitter voltage	I <sub>C</sub> = 1 mA	$V_{CEO}$	90			V		
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7			V		
Collector ermitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}$	I <sub>CEO</sub>			150	nA		
COUPLER								
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V <sub>CEsat</sub>			0.3	V		
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega$	f <sub>c</sub>		110		kHz		
Coupling capacitance	f = 1 MHz C <sub>k</sub>			0.3		pF		

#### Note

Minimum and maximum values are tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

www.vishay.com 790 For technical questions, contact: optocoupleranswers@vishay.com

Document Number: 83532 Rev. 1.7, 28-Oct-09

 $<sup>^{(1)}</sup>$   $T_{amb}$  = 25  $^{\circ}$ C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

 $T_{amb} = 25 \, ^{\circ}C$ , unless otherwise specified.



CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		TCDT1120	CTR	10			%
		TCDT1120G	CIN	10			70
		TCDT1122	CTR	15			%
	V - 5 V I - 1 m A	TCDT1122G	CIN	15			70
	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 1 mA	TCDT1123	CTR	30			%
		TCDT1123G	CIR	30			70
		TCDT1124	CTR	60			%
		TCDT1124G					70
I <sub>C</sub> /I <sub>F</sub>	V 5V1 40 40	TCDT1120	CTR	40			%
		TCDT1120G					70
		TCDT1122	CTR	63		125	%
		TCDT1122G				123	70
	$V_{CE} = 5 \text{ V}, I_{F} = 10 \text{ mA}$	TCDT1123	CTD	100		000	%
		TCDT1123G	CTR	100		200	70
		TCDT1124	CTR	160		320	%
		TCDT1124G	CIN	100		320	70

MAXIMUM SAFETY RATINGS (1)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT	INPUT							
Forward current		I <sub>F</sub>			130	mA		
OUTPUT								
Power dissipation		P <sub>diss</sub>			265	mW		
COUPLER	COUPLER							
Rated impulse voltage		V <sub>IOTM</sub>			6	kV		
Safety temperature		T <sub>si</sub>			150	°C		

#### Note

<sup>(1)</sup> According to DIN EN 60747-5-5 (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Partial discharge test voltage - routine test	100 %, t <sub>test</sub> = 1 s	$V_{pd}$	1.6			kV		
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 2)	$V_{IOTM}$	6			kV		
lot test (sample test)		$V_{pd}$	1.3			kV		
	V <sub>IO</sub> = 500 V	R <sub>IO</sub>	10 <sup>12</sup>			Ω		
Insulation resistance	$V_{IO} = 500 \text{ V}, T_{amb} \leq 100 \text{ °C}$	R <sub>IO</sub>	10 <sup>11</sup>			Ω		
	V <sub>IO</sub> = 500 V, T <sub>amb</sub> ≤ 150 °C (construction test only)	R <sub>IO</sub>	10 <sup>9</sup>			Ω		

Document Number: 83532 Rev. 1.7, 28-Oct-09

# Vishay Semiconductors Optocoupler, Phototransistor Output



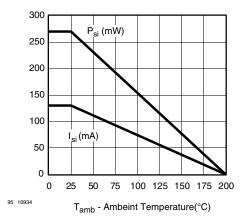


Fig. 1 - Derating Diagram

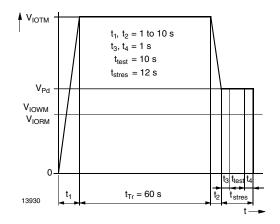


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5/DIN EN 60747-; IEC 60747

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		TCDT1120			10		^
		TCDT1120G	- I <sub>F</sub>		10		mA
Current time	V F V D 100 O (con figure 2)	TCDT1123			10		A
Current time	$V_S = 5 \text{ V}, R_L = 100 \Omega, \text{ (see figure 3)}$	TCDT1123G	- I <sub>F</sub>		10		mA
		TCDT1124	1_		10		mA
		TCDT1124G	- I <sub>F</sub>		10		IIIA
		TCDT1120	+_		2.5		116
		TCDT1120G	t <sub>D</sub>		2.5		μs
Delay time	$V_S = 5 \text{ V}, R_L = 100 \Omega$ , (see figure 3)	TCDT1123	+_		2.8		116
Delay time	vg = 5 v, ri_ = 100 sz, (see rigure 5)	TCDT1123G	t <sub>D</sub>		2.0		μs
		TCDT1124	t <sub>D</sub>		2		μs
		TCDT1124G	ι)				μδ
		TCDT1120	- t <sub>r</sub>		3		μs
		TCDT1120G					μο
Rise time	$V_S = 5 \text{ V}, R_L = 100 \Omega$ , (see figure 3)	TCDT1123	- t <sub>r</sub>		4.2		μs
Tiloc time	VS = 0 V, Ti_ = 100 12, (000 figure 0)	TCDT1123G			7.2		μο
		TCDT1124	t <sub>r</sub>		4		μs
		TCDT1124G			7		μο
		TCDT1120	- t <sub>s</sub>		0.3		μs
		TCDT1120G	-8		0.0		μο
Storage time	$V_S = 5 \text{ V}, R_L = 100 \Omega, \text{ (see figure 3)}$	TCDT1123	t <sub>s</sub>		0.3		μs
Ctorago anno	15 = 0 1, 11 = 100 12, (000 ligate 0)	TCDT1123G	-5				μο
		TCDT1124	- t <sub>s</sub>				μs
		TCDT1124G	•5		0.0		μο
		TCDT1120	t <sub>f</sub>		3.7		μs
		TCDT1120G	7		J.,		F
Fall time	$V_S = 5 \text{ V}, R_L = 100 \Omega, \text{ (see figure 3)}$	TCDT1123	t <sub>f</sub>		4.7		μs
	13 0 1, 120 12, (200 ligation)	TCDT1123G	*1				F.5
		TCDT1124	t <sub>f</sub>		4.7		μs
		TCDT1124G	"				



SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		TCDT1120					
		TCDT1120G	- t <sub>on</sub>		5.5		μs
Turn-on time	$V_S = 5 \text{ V}, R_L = 100 \Omega$ , (see figure 3)	TCDT1123			7		
rum-on time	V <sub>S</sub> = 3 V, n <sub>L</sub> = 100 s <sub>2</sub> , (see lightle 3)	TCDT1123G	- t <sub>on</sub>		1		μs
		TCDT1124	+		6		116
		TCDT1124G	t <sub>on</sub>		U		μs
		TCDT1120	+		4		μs
		TCDT1120G	t <sub>off</sub>		7		μο
Turn-off time	$V_S = 5 \text{ V}, R_L = 100 \Omega, \text{ (see figure 3)}$	TCDT1123	t <sub>off</sub>		5		μs
rain on time	V5 = 0 V, T1 = 100 32, (300 light 0)	TCDT1123G	•оп				μο
		TCDT1124	- t <sub>off</sub>		5		μs
		TCDT1124G					μο
		TCDT1120	- t <sub>on</sub>		16.5		μs
		TCDT1120G					μο
Turn-on time	$V_S = 5 \text{ V}, R_L = 1 \text{ k}\Omega, \text{ (see figure 4)}$	TCDT1123	- t <sub>on</sub>		21.5		μs
	13 5 1, 1.2 1 1.23, (222 1.321 1.7	TCDT1123G					ļ. ·
		TCDT1124	- t <sub>on</sub>		20		μs
		TCDT1124G	-011				ļ. ·
		TCDT1120	- t <sub>off</sub>		22.5		μs
		TCDT1120G	-011				P. V
Turn-off time	$V_S = 5 \text{ V}, R_L = 1 \text{ k}\Omega$ , (see figure 4)	TCDT1123	t <sub>off</sub>		37.5		μs
		TCDT1123G	-011				<u>'</u>
		TCDT1124	t <sub>off</sub>		50		μs
		TCDT1124G	Oii				r ·

### **TYPICAL CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

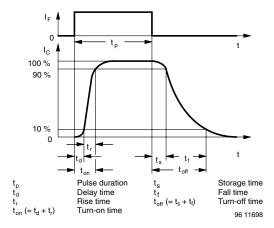


Fig. 3 - Switching Times

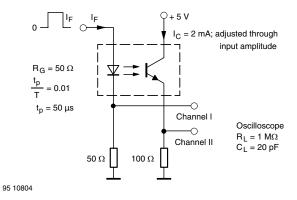


Fig. 4 - Test Circuit, Non-Saturated Operation

# Vishay Semiconductors Optocoupler, Phototransistor Output



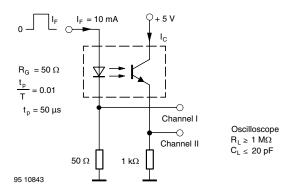


Fig. 5 - Test Circuit, Saturated Operation

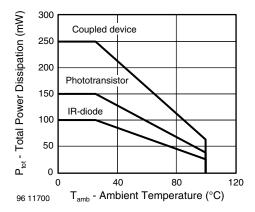


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

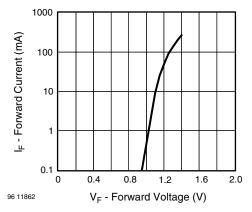


Fig. 7 - Forward Current vs. Forward Voltage

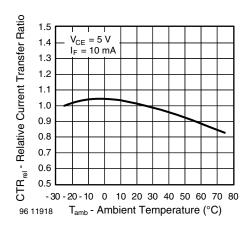


Fig. 8 - Relative Current Transfer Ratio vs. Ambient Temperature

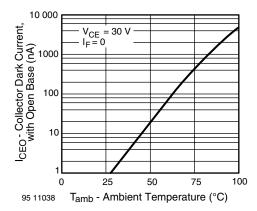


Fig. 9 - Collector Dark Current vs. Ambient Temperature

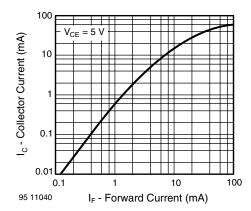


Fig. 10 - Collector Current vs. Forward Current



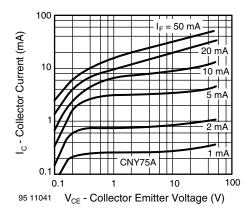


Fig. 11 - Collector Current vs. Collector Emitter Voltage

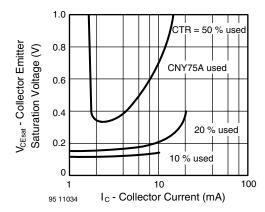


Fig. 12 - Collector Emitter Saturation Voltage vs. Collector Current

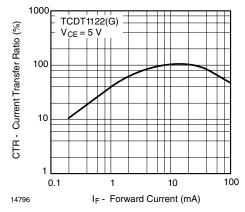


Fig. 13 - Current Transfer Ratio vs. Forward Current

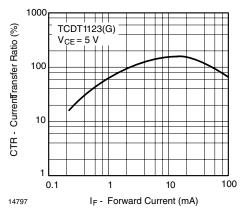


Fig. 14 - Current Transfer Ratio vs. Forward Current

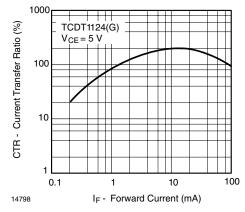


Fig. 15 - Current Transfer Ratio vs. Forward Current

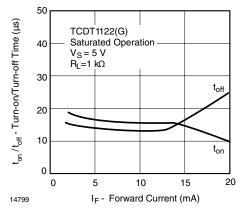


Fig. 16 - Turn-on/off Time vs. Forward Current

# Vishay Semiconductors Optocoupler, Phototransistor Output



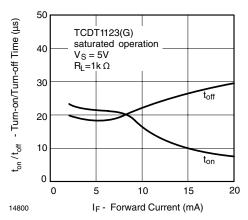


Fig. 17 - Turn-on/off Time vs. Forward Current

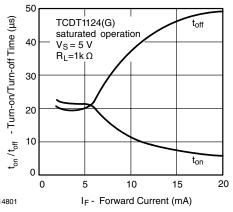


Fig. 18 - Turn-on/off Time vs. Forward Current

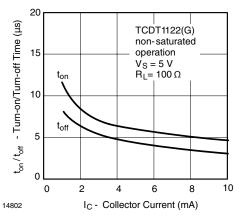


Fig. 19 - Turn-on/off Time vs. Collector Current

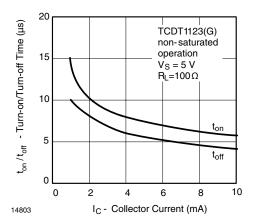


Fig. 20 - Turn-on/off Time vs. Collector Current

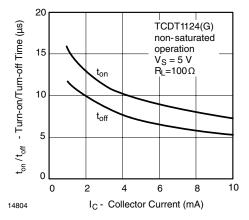
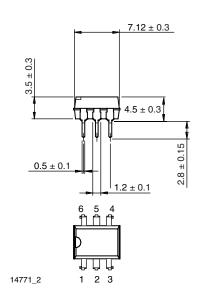
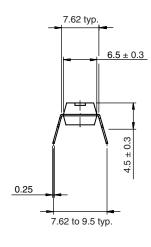


Fig. 21 - Turn-on/off Time vs. Collector Current

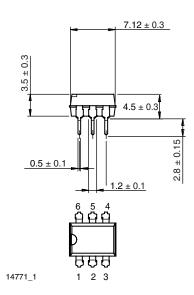


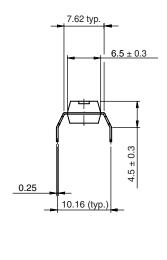
# **PACKAGE DIMENSIONS** in millimeters **DIP-6**



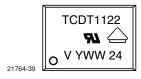


### DIP-6, 400 mil





## **PACKAGE MARKING**



#### Note

Example of making used for the TCDT1122 and TCDT1122G



Vishay

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